Рабочее совещание по неупругому рассеянию нейтронов СПЕКТРИНА - 2018 19 - 20 апреля 2018 г., ПИЯФ НИЦ «КИ», г. Гатчина

Спиновые флуктуации и магнетизм в системах с валентной нестабильностью

П.А. Алексеев

Физика как секс: может не давать практических результатов, но это не повод ею не заниматься Р. Фейнман Все, что интересно, – не просто. Следствие: когда начинаешь вникать, то получаешь то, чего не ждал... Рабочее совещание по неупругому рассеянию нейтронов СПЕКТРИНА - 2018 19 - 20 апреля 2018 г., ПИЯФ НИЦ «КИ», г. Гатчина

Spin fluctuations and magnetism in systems with valence instability

P A Alekseev

Spin fluctuations and magnetism Rare-earth based compounds with *f*-electron instability

Spin fluctuations are inherent to systems with unfilled and virtually unstable *f*- and *d*- electron shells. Example – systems based on the f-elements from the beginning middle and on the f-elements from

the <u>beginning, middle</u>, and <u>end</u> of rare earth series (*Ce, Sm,Eu, Yb*).

"Kondo effect, heavy fermions" Scattering of electrons with spin reversal

"Valence fluctuations" Symbolic $f^n \rightarrow f^{n-1} + e$ From early 80th...

Commonplace: spin (valence) fluctuations (τ_{sf}) – physical reason for the formation of the nonmagnetic ground state (no LRMO and static MM):

 $(\tau_{sf})^{-1} > kT => effective suppression of the MM on <math>\downarrow T$ (HF-, MV-systems)

For selected nonmagnetic systems the formation of semiconducting state with gap ~ 100K is specific!

Also spin-gap and singlet ground state are formed.

<u>This is mixed valence semiconductor or "Kondo insulator" (KI)</u> Recently KI with magnetic ordering (LRMO) were discovered! Spin fluctuations is the dynamical effect therefore magnetic neutron spectroscopy is the adequate experimental method

How it was started with neutrons?

from diffraction - to INS

Neutron magnetic form factor – is peculiar to any neutron scattering data

Physical origin of the form factor F(Q)

The result of interference of neutron wave scattered (with momentum transfer **Q**) by the electron shell (*in fact* – *on the magn. moment density,originated from 1*) <u>spin</u> and 2) <u>orbital</u> moments of electrons).

Furrier transform of magnetization density distribution

Forward scattering – no interference, F(0) = 1Increase of scattering angle or/and neutron energy, (that means increase of the momentum transfer Q) results in $F(Q) \rightarrow 0$

Magnetic form factor basically is defined experimentally from:
1) Intensity of Bragg peaks <u>in diffraction</u> for ordered state ,
2) In paramagnetic state, form induced moment in external magnetic field by <u>polarized neutron diffraction</u>

In the most of real cases a dipole approximation (small Q) is used: $F(Q) = \langle j_0(Q) \rangle + [(2/g) - 1] \langle j_2(Q) \rangle, g - Lande factor$

Spin + orbital Orbital

Spin fluctuations and magnetism

1. Magnetic form factor in intermediate valence state of Sm and Eu

1.1 The form-factor "puzzle" of intermediate valence Sm-ions For a long time it was not clear, why there is **no evidence** of the presence of "*Sm*³⁺ - like form-factor" in neutron measurements for intermediate valence *Sm*-based systems - *SmS* ("gold") and *SmB*₆, - in spite of the fact that the average valence for Sm is close to 2.5

Intramultiplet $(\Delta J=0)$ $f(Q)=\langle j_0 \rangle + C_2 \langle j_2 \rangle$ $C_2=(2-g_J)/g_J$

Intermultiplet inelastic spinorbital transitions $(\Delta J \neq 0) C_2 = -1$ $f(Q) = \langle j_0 \rangle - \langle j_2 \rangle$ $< j_n > -$ are integrals of the product of the 4f radial wave function and spherical Bessel functions of n-order $< j_n > -$ associated with both

 $< j_0 > -$ associated with both spin and orbital moments,

 $< j_2 > -$ resulted from the orbital moment alone

 C_2 for Sm³⁺ is very high due to collision of J=5/2, L=5, S=5/2





A little more details about INS results for mixed valence systems

Inhomogeneous mixed valence system Sm_3Te_4 with spin-glass formation below $T_q=1.5K$



Intermultiplet (spin-orbit) excitations



Low energy ("resonant") mode in SmB6



Low energy ("resonant") mode in SmB6

154 5m "B6 single crystal



Low energy ("resonant") mode in SmB6



Q-dependence of form-factor with valence change (along [111] for single crystals) Energy - valence correspondence

Does it mean that RM is a "double" of intermultiplet J=0→J=1 (f⁶:Sm²⁺) transition (singlet-triplet) for IV state of Sm !? "Help" (important detailes) comes from SmS Relation between spectral structure (with corresponding form-factors) and temperature for SmB_6 IV-state *)



*) P. A. Alekseev, J.-M. Mignot, P.S. Savchenkov, V.N. Lazukov JETP Letters 103 (10) 636 (2016)

Summary of low T experimental data for FF of SmB_6 including <u>quasielastic signal at T=100K</u>



Structure and properties of the ground state wave function of IV state are reflected by form-factor measurements

Form-factor measured depends from type of experiment and conditions of measurements

$$\chi_{C}^{m}(T) = (g_{J}\mu_{B}^{2}/k_{B}T) \left| \langle m\hat{J}_{z}m \rangle \right|^{2} \exp(-\beta E_{m})/Z$$
$$\chi_{VV}^{nm}(T) = 2g_{J}\mu_{B}^{2} \frac{\left| \langle n\hat{J}_{z}m \rangle \right|^{2}}{\Delta_{nm}} \exp(-\beta E_{m})/Z$$

For neutron spectroscopy:



$$\chi''(\vec{Q},\omega,T) = \pi\hbar\omega \left[\sum_{m} f_{m}^{2}(\vec{Q},T)P_{mm}(Q,\hbar\omega,T)\chi_{C}^{m}(T) + \frac{1}{2}\sum_{m\neq n} f_{mn}^{2}(\vec{Q},T)P_{nm}(Q,\hbar\omega-\Delta_{nm},T)\chi_{VV}^{mn}(T)\right]$$

<u>SmB₆ at low T</u>: spin gap, - singlet ground state+excitation at 14meV(RM) + Spinorbitals from Sm²⁺ and Sm³⁺ "parent"= <u>only Van-Vleck contribution</u>

<u>SmB₆ at high T</u>: spin gap is closed, manifold of "parent" state is available = <u>quasilestic signal results from Curie contribution</u>: $T_{eff} \sim T_{sf} \propto (\Gamma_{QE}, \Gamma_{SO})$

$$f_{\text{QE}}^2(Q,T) = \sum_i v \,\sigma_{2,i} \,\rho_{2,i}(T,J) f_{2,i}^2(Q,T) + \sum_i (1-v) \,\sigma_{3,i} \,\rho_{3,i}(T,J) f_{3,i}^2(Q,T)$$

2, 3 - corresponds to Sm²⁺ and Sm³⁺, respect.

Form factor of QE-signal for SmB₆ (measured at 100K)



Summary: form-factor measurements in relation to the specific of corresponding spectral function can provide the hint to character of *f*-electron wave function for intermediate valence state

1.2 Form-factors for intermediate valence Eu-ions in $EuCu_2Si_2^*$



*) P S Savchenkov, P A Alekseev, A Podlesnyak, A I Kolesnikov, K S Nemkovski, Intermediate-valence state of the Sm and Eu in SmB6 and EuCu2Si2: neutron spectroscopy data and analysis J. Phys.: Condens. Mater 30 (5, 7Febr)) (2018) 055801

EuCu₂Si₂



for **M2** form factor $F_{M2}(Q) \sim \langle j_0(Q) \rangle - \langle j_2(Q) \rangle$, SO-excitation but for **M1** – form factor is $F_{M1}(Q) \sim \langle j_0(Q) \rangle$, J=S, L=0! : f^7

Resonant mode (**M1**) carries evidence of the high spin state (f⁷) presence at low temperatures for intermediate valence state of Eu This could be the prerequisite for the development of the magnetism at some point of phase diagram We will omit the quantum mechanics consideration of the ground state wave function of intermediate valence state and its generalization for the case of Sm and Eu as well (special people exist for that!)

Also not going into very interesting physics for a family of 1-2-2 Eu - based systems...

Just stop at the $EuCu_2$ ($Si_{1-x}Ge_x$)₂, for some details of magnetism....

Spin fluctuations and magnetism

2. Spin fluctuations and long range magnetic order: the case of "strong" ($v \sim 2.5$) and flexible intermediate valence

How the magnetic correlation can survive under these conditions?! **Particular example:** Valence is

staying homogeneous:

 $EuCu_2(Si_xGe_{1-x})_2$



EuCu₂(Si_xGe_{1-x})₂ : magnetic phase diagram



What is the origin of this phase diagram ?

Two "competing" states for intermediate valence Europium: <u>Eu³⁺ (f⁶, like Sm²⁺) J=0(!)</u>, ${}^{7}F_{0} \rightarrow {}^{7}F_{1}$ SO-transition:E=46meV, σ =7.34 barn, Eu²⁺ (f⁷, like Gd³⁺) J=S=7/2, σ =38.51 barn (NO inelastic excitations) **Then to neutron spectroscopy data: ISIS (HET, MARI) and ILL (IN-4C)**



-Some region of x-concentrations appears where LRMO (k=1/3,0,0) coexists with spin fluctuations peculiar to homogeneous IV observed for any x (but NO model !)

-This region verge on HF state similar by spectral characteristics to ones of generic HF systems based on Ce, Yb (BUT "strong" IV !)

Quasielastic width (T=100...200K) and strength of mixed valence in $EuCu_2(Si_xGe_{1-x})_2$



2.1 Summary IV and LRMO: competition and coexistence

Formation of the magnetic ground state for IV *Eu* is provided by the <u>rearrangement of the magnetic excitation spectrum</u> of the system caused by the decrease of valence from **3**- δ down to **2**+ δ . Just this rearrangement, probably, is a *background of a sequence of* phase transformations for *EuCu₂(Si_xGe_{1-x})₂* : 30 2.2 valence 2.8



-Moderate <u>spin fluctuations (SF) assist</u> to appearance of **heavy fermion** (**HF)** state

Further slowing down of SF result in LRMO for reduced moments on *Eu*.
 In some sense – analogy with Ce-based (LRMO-HF) systems, but!!!
 The valence is very far from integer!

- The elaboration of the adequate physical model is indispensable for understanding of physics behind the <u>coexistence of SF and LRMO</u>.

3. Magnetic impurity effect in Kondo-insulator *)

 SmB_6 with Gd^{3+} - impurity (J=S=7/2, concentration from 0.04% up to 5%)

specific heat and impurity magnetic moment screening scales systematically in SmB_6

both depends from the exchange constant and electron density of states on E_F -($J\eta$) - which modifies with impurity concentration

 $J\eta$ -parameter scaled collapse of *specific heat* ties the low temperature DOS to the reduced impurity moment. This indicates the involvement of impurity magnetism in the low energy DOS of Gd doped samples

^{*)} W. T. Fuhrman, J. R. Chamorro, P. Alekseev, J.-M. Mignot, et al Screened moments and extrinsic in-gap states in samarium hexaboride, preprint arXiv:1707.03834, 2017. 2, 2017

Reduction of the Gd³⁺ effective magnetic moment M_{imp} (μ_B /Gd) in magnetization of SmB₆ with Gd impurity



Kondo screening?!

Influence of the Gd impurity on the electronic heat capacity of SmB₆



Enhancement of the electronic DOS!?

Relaxation width of resonance mode as function of temperature in SmB6



 $\Omega \sim \Delta = 14 \text{ meV} - \text{mode energy or spin-gap}$

 $\Gamma_0 = \Gamma_{J\eta} = 4\pi (J\eta)^2 \Omega \sim 0.1 \text{meV}$ for Gd: 0.04% ("isotopic pure sample")

Intrinsic width Γ_0 dramatically depends from $J\eta$ which characterizes impurity effect on the electronic system: just few % of Gd will increase relaxation ~10² times

Allow to explain the suppression of RM in YbB_{12} by Tm - impurity?!

Подавление резонансной моды и переход в режим «квазищели»

по мере роста концентрации магнитных ионов Тт



Spin fluctuations and magnetism in systems with valence instability

Conclusion

Exotic magnetic behaviour appears as a consequence of the coexistence and competition of different *f*-electron interactions in solids

Neutron spectroscopy – very effective instrument for clarifying the principal features of the exotic magnetic behaviour – that is the way to understanding exotic phenomena....

Благодарю за внимание

Удачи на «Большой дороге» науки!



Most scientists regarded the new streamlined peer-review process as 'quite an improvement.'

RM - low energy symmetry analogue for intermultiplet transition $JO \rightarrow J1$ of Sm(2+) or Eu(3+) configuration

Variation of Sm-valence results in the variations of <u>energy</u> and <u>Q-dependence of intensity</u> for RM. Similar effects for Eu valence variation. Such behaviour may be understood on the base of model, which relates the delocalization extent of f-electron and RM energy with Sm-valence value ("excitonic model" of Michshenko & Kikoin)



K.W.H. Stevens, J.Phys.C 11 (1978), K.A. Kikoin, J.Phys.C 17 (1984)


2.1 *EuCu*₂(*Si*,*Ge*)₂ –IV and LRMO: competition and coexistence

Системы *ReTm₂X₂* («1-2-2»)

Re = Ba,...Nd, Sm, Eu, Gd...; Tm = Cu, Fe, Ni, Co...; X = P. As. Se. Si. Ge...

Wide class of isostructural compounds, including Cu-free intermetallic superconductors (T_c~30...50K)

Physical properties: moderately anizotropic metals, for Re = Eu the combinations are possible:

Long range magnetic order (LRMO)Superconductivity $(T_c \sim T_N)$ (SC)Intermediate valence (IV)



 $EuNi_2(Si_{1-x}Ge_x)_2 LRMO/IV; EuFe_2(As,P)_2, EuFe_2As_2 LRMO/SC/IV$

EuCu₂(Si,Ge)₂ – distinguished from others Eu-based systems by the existence of the area of *heavy fermion* behaviour between *LRMO* and *IV* states on phase diagram

EuCu₂(Si_xGe_{1-x})₂ phase diagram (from thermodynamics, transport and X-ray spectroscopy)

(Z. Hossain et.al. PRB 69 (2004) 014422)



^{*)} The first indication of Kondo behaviour for x >0.7 is in *E.M. Levin, B.S. Kuzhel, O.I. Bodak, e.a. Phys. Stat. Solidi B* **161**, 783 (1990)

^{**)} K. S. Nemkovski, D. P. Kozlenko, P. A. Alekseev, J.-M. Mignot, e.a., Phys. Rev. B 94 195101 (2016)

Источник многообразия f-c hybridisation свойств СКЭС – три взаимодействия. Crystal exchange interaction Подавление резонансной моды и переход в режим «квазищели» по мере роста концентрации магнитных ионов Тт Гибридизация ЭСТИ. T=2K d) T=2K T=2K 20 YbB12 Yb0.85Tm0.15B12 Yb0.92Tm0.08B12 1200 ŵ 0 10 Energy (meV) 0 10 Energy (meV) a 1000 T=80K Без квази упургой YbB12 Temperature (K) 800 компоненть α-Ce γ-Ce ê T=2K 20 Yb1-xTmxB12 critical ((U, O)S >=m 600 X=0.08 X=0.15 S(Q,E) (mbarn sr -10 0 10 Energy (meV) 20 30 400 slope = 200 0 10 Energy (meV) 20 -10 $T_0 = \frac{\Delta}{\Delta}$ 24 25 23 26 27 19 21n Atomic Volume (Å³) 60 10 30 40 50 70 Pressure (kbar) **Pu:** δ - α, **P** ~2κ6ap ^{**)} Се γ - α переход, (Bridgman, 1931^{*}) $\Lambda V/V \sim 15\%$ $\Lambda V/V \sim 25\%$

*)P.W. Bridgman, The Physics of High Pressures, G. Bell and Sons, Ltd., London, 1931, p. 267. **)"Challenges in Plutonium Science", ed. N.G. Cooper, Los Alamos Science, Number 26, 2000

2.2. Novel insight into Kondo-insulators : the 1-2-10 family

Specific features:

-Magnetic ordering in Ce-based systems (Kondo-insulators) with charge (and spin) gap;

-Relatively high T_N for relatively small magnetic moments

*"*1 – 2 – 10 family*"*



CeOs₂Al₁₀



Ce³⁺



Mixed-valence



Adroja, Phys Rev B 87, 224415 (2013).

«Real» (generic) Kondo insulators

Generally *nonmagnetic* ground state

SmB₆, (Sm,Y)S, YbB₁₂ CeNiSn, CeRhSb, Ce₃Bi₄Pt₃ Ce T_4 Sb₁₂, UFe₄P₁₂, U₂Ru₂Sn ... FeSi (?)





LnM_2AI_{10} crystal structure



$CeRu_2AI_{10} - KI + low - T$ phase transition





- Stronger anisotropy (*a* = easy axis)
- • $\rho(T)$: negative slope, activation law

Ordered phase $T < T_0$

- Exponential dependences of χ and C_p:
 (Δ ~ 100 K) partial gap opening at the Fermi surface
- Under *P* : insulating state first enhanced, then suppressed above 2 GPa.

Magnetic order is unconventional



Antiferromagnetic order from neutron diffraction



Anisotropic magnon picture for CeRu₂Al₁₀



RPA calculation (code: Sylvain Petit)

Crystal field parametersStrigari, PRB (2012)

 $(B_2^0, B_2^2, B_4^0, B_4^2, B_4^4) = (-1.326, -29.236, +1.013, -1.747, -5.317) \text{ K}$

Anisotropic exchange $\mathcal{H}_{i,j} = \sum_{\alpha} \mathcal{J}^{\alpha} S_i^{\alpha} S_j^{\alpha}$

TABLE I. Anisotropic exchange parameters (in units of K) used in the RPA calculation. Atomic positions (x_i, y_i, z_i) , $i = 1: (0, y, \frac{1}{4}); 2: (\frac{1}{2}, \frac{1}{2} + y, \frac{1}{4}); 3: (\frac{1}{2}, \frac{1}{2} - y, \frac{3}{4}), 4: (0, -y, \frac{1}{4})$ $\frac{3}{4}$), with y = 1.1239(3) [23].

| Ce pairs (i, j) | \mathcal{J}^a | \mathcal{J}^b | \mathcal{J}^c |
|-------------------|-----------------|-----------------|-----------------|
| (1,4); (2,3) | 2.7 | 2.7 | 58 |
| (1,3); (2,4) | -0.9 | -0.9 | -0.9 |
| (1,2); (3,4) | 1.1 | 1.1 | 1.1 |



M.M. three times(!) higher than experimental

- •"Simple" CF + anisotropic exchange model *not* sufficient.
- •Role of (anisotropic) "*c-f*" <u>hybridization</u> with Ce ligands ? Sera, JPSJ (2013):
- Structure: maximum deviation from lanthanide contraction occurs along *a*, negligible along *b*
- NMR:strong transferred hyperfine field (1158 Oe) at AI[2] site, located along *a* direction with respect to Ce site.

<u>Suggestion</u>: hybridization occurs primarily along the *a* direction (Ce–Al[2])





Обычно справедливо дипольное приближение, когда F(Q)=<j₀>(Q)+[(2/g)-1] <j₂>(Q)



спин+орбита

<j_n(Q)> are integrals of the product of the spherical Bessel

distribution of the electron

density, derived from a Dirac-

Fock relativistic calculation.

function of order *n* and the radial

Для ПВ-состояния sm υ≅ 2.5 орбита

Sm³⁺: $4f^{5}5s^{2}p^{6}$ $^{6}H_{5/2}$



(2-g)/g=6!

Возможно «смешивание» Sm²⁺ и Sm³⁺состояний из-за «флуктуаций» типа: Sm²⁺ Sm³⁺ + e⁻

Combined form factor

Магнитный момент равен 0!

Beginning of the story....late 80th Composite crystal ¹⁵⁴Sm¹¹B₆ V~0.8cm³





BCC, a=4.13A

Short introduction:

What are Kondo-Insulators?

What are valence unstable (intermediate / mixed) valence systems?

What is an interest with that?!

What are Kondo-insulators?

"Valence fluctuations" are inherent to systems with unfilled and virtually unstable *f*-и *d*-electron shells.

Example – systems based on the f-elements from

the beginning, middle, and end of rare earth series.

Symbolic presentation $f^n \rightleftharpoons f^{n-1} + e$ From the early 80th...

"Commonplace": valence fluctuations (τ_{sf}) – physical reason for the formation of the nonmagnetic ground state:

 $(\tau_{sf})^{-1} > kT = supression of the m.m. on <math>\downarrow T$ (like HF-, MV-systems...)

For selected nonmagnetic systems the formation of semiconducting state with gap ~100K is specific!

This is mixed valence semiconductor or "Kondo insulator"

Recently KI with magnetic oredering (LRMO) were discovered!

What are Kondo-insulators!

CeNiSn, Ce₃Bi₄Pt₃, Ce₃Sb₄Pt₃,CeRhSb,... SmB₆, SmS(P>6 kbar) YbB₁₂! U₃Sb₄Pt₃, U₂Ru₂Sn,...

FeSi (?)

"High temperature" limit: poor metal with local magnetic moment and Kondo-effect

"Low temperature" limit (ground state) : semiconductor (gap ~100 K) with zero magnetic moment

The most of the Kondo-insulators have fractional occupation of the f-shell (*homogenous mixed valence (MV) state*)

The strong correlations are important both for the spin- and for charge- subsystems.

Specific properties originated from f-electrons and are essentially dynamical effect: therefore the neutron spectroscopy – is a powerful tool!

What are Kondo-insulators?!

This kind of SCES usually are considered as one "family"... Perhaps, such treatment is too much simplified? Indeed!

Neutron spectroscopy (inelastic magnetic neutron scattering) results in discovery of the "resonant mode" phenomenon for mixed valence systems like "Kondo-insulators" and some others...

The most bright examples – MV semiconductors, like: -SmB₆ и SmS (strong MV), and -YbB₁₂ (weak MV).

The physical result: There are established two different in nature (but in both cases singlet !) types of the ground state.

What was initially expected from neutron scattering experiments with MV systems?

Semiconductors with "strong" intermediate valence

Formal (average) valence is far from integer value

SmB₆, SmS "classical" examples

 f^6 f^5 + electron in conduction band $Sm^{2+} \stackrel{\longrightarrow}{\longrightarrow} Sm^{3+}$

What is the structure of the magnetic excitation spectra and its response on the variation of temperature and valence? One could expect spin-orbit multiplet structure of f6 and f5 configurations to appear...at least!

Important - NO CEF effects expected due to valence fluctuation!

Intermultiplet (spin-orbit) excitations



Low energy ("resonant") mode in SmB6



Low energy ("resonant") mode in SmB6

154 5m "B6 single crystal



What about an interplay of intermediate valence and magnetism (spin fluctuation vs ordering?)

SmS in IV state is a good model system

In SmS dispersive magnetic excitation for intermultiplet transition J0→J1 is observed by neutron scattering due to exchange interaction Sm-Sm

SmS: P = 6 кбар EPT to "golden" phase, valence~2.7

Sm(Y)S: "chemical pressure" with continuous EPT



Excitations and Sm-Sm exchange in SmS



Excange interaction parameters in SmS: $J_1=0.043$ $J_2=0.020$ $J_3=-0.003$



Dispersion of energies and relative intensities for magnetic peak MSO and Mexc



Introduction of the interaction (hybridization) between M_{so} and M_{EXC} allows to describe the experimentally observed E(q) and I(q)

Intensities of two modes in Sm(Y)S as functions of momentum transfer Q

Valence of Sm ~ 2.35



-Interaction Sm-Sm do exists → strong energy dispersion appears

-Both modes are of the same symmetry → exchange of intensity in BZ

-The origin of the exictation M_{exc} identical to resonant mode of SmB6 \rightarrow more steep formfactor for low energy peak!

Spin gap, singlet ground state are exsiting in Sm(Y)S as well as in SmB₆

Q// [111], [110], [001]



Ce-based IV system with spin-gap: CeNi

LaNi –diamagnetic CeNi – param - Intermediate valence: v(10K)~3.15 PrNi – ferromag T_C = 21K ("induced" magnetism) NdNi –ferromag T_C = 31K



Magnetic excitation in spin-gap of CeNi spectrum





Spin fluctuations and magnetism

2. "Resonance" mode (RM) in Sm-based intermediate valence systems: single-site and cooperative behaviour

RM appears due to formation of a singlet ground state for intermediate valence compound How the magnetic correlation can survive under these conditions?

EuCu₂(Si_xGe_{1-x})₂ : definition and characterization of valence state *"Fast" and "slow" technique*

L₃-edge (*T*~10⁻¹⁵s): mixed "valence"



EuCu₂(Si_xGe_{1-x})₂ : determination of magnetic state Neutron diffraction (x=0.0, 0.4, 0.6)

Diffractometer 7C2 ("hot" neutron source, LLB), λ =1.121 Å, 2 Θ =3⁰ – 40⁰ , m_s~0.6g



propagation vector $\mathbf{k} = (1/3 \ 0 \ 0)$. The Eu magnetic moments located at positions (0 0 0) and (1/2 1/2 1/2) of the crystal structure have antiparallel orientation. They are located in the (*bc*) planes and oriented at the angles $\varphi = 33^{\circ}$ (147°) with respect to crystallographic *c* - axis

Eu-ion static magnetic moment from the diffraction data at the temperature T=5K. X (EuCu₂(Si_xGe_{1-x})₂) M_x , $\mu_B M_y$, $\mu_B M_z$, $\mu_B M_{tot}$, μ_B **R**-factors Т_№,К 0.0: $EuCu_2Ge_2$ 3.1 6.0 6.7(1) Rp =0.07, Rwp = 0.09 15 0.4: EuCu₂Si_{0.8}Ge_{1.2} 5.3(1) Rp = 0.09, Rwp = 0.123.3 4.1 19 0.6: EuCu₂Si_{1.2}Ge_{0.8} Rp =0.05, Rwp = 0.07 2.6 5.3(1) 17 4.6

MM (Eu²⁺) = $7.94\mu_B$

EuCu₂(Si_xGe_{1-x})₂ : inelastic magnetic neutron scattering





Decrease of the excitation energy and closing of spin-gap result in **formation of magnetic ground state for IV Eu** at X decreasing to~0.75

Eu-Eu interaction is mediated by conduction electrons not like in TmSe
Magnetic excitations in $EuCu_2(Si_xGe_{1-x})_2$



effect of Ge for Si substitution:

- suppression and broadening of both M1 and M2
- •further shifting of both M1 and M2 towards low energies;
- appearance of quasielastic scattering signal already at low temperature (at least for x=0.75)
- at x=0.6: inelastic peaks are shifted below 10 meV or suppressed; QE-signal is narrow and exists starting from the low temperature

Experimental data for $EuCu_2(Si_{1-x}Ge_x)_2$, TOF spectrometers (HET, MARI) $E_0=100meV$





3.2 Intermediate valence (IV) and magnetism: TmSe

How the LRO state is formed under the condition of IV state of Tm? Coherent state appears obviously, but which way it is realized?

The key question is the origin of "resonance mode" (inelastic excitation) in the spectra of LRO state of TmSe

In theoretical approaches to the description of IV state for Tm the existence <u>of</u> <u>two magnetic configurations</u> is supposed simultaneously for f-electrons under the conditions:

- <u>spacial</u> [**1,2**] or

- <u>time</u> [3] coherence for spin fluctuations between two magnetic configurations

By studying the effect of substitution for *Tm* by other ions [4] it was shown – the origin of "resonance mode" is single site - this corresponds to the *time coherence* [3] as a source of LRO.

- 1. A.J. Fedro, S.K. Sinha, in: Valence Fluctuations in Solids, eds. L.M. Falikov, W. Hanke and M.B. Maple (North-Holland, New Yourk, 1981) p. 329
- 2. M. loewenhaupt, E. Holland-Moritz, J. Appl. Phys. 50(11)7456 (1979)
- 3. J. Mazzaferro, C.A. Balsiero, B. Alascio, PRL 47 (1981) 274
- 4. E. Holland-Moritz, JMMM, 38 (1983) 253-263

3. 2 Transition from heavy fermion to magnetically ordered state on temperature decrease





FIG. 5. Quasielastic linewidths vs temperature for $CeAu_2Si_2$ (\bullet Lorentzian, \circ Gaussian), $CePd_2Si_2$ (\blacktriangle) and $CeRh_2Si_2$ (\blacklozenge). The arrows indicate the Néel temperatures. The solid lines are guides to the eye.

QE-signal exists at some T below T_N !

A. Severing, E. Holland-Moritz, B. Frick, PRB 39 (7) 4164 (1989) etc

3.2 Intermediate valence and magnetism: TmSe

TmSe (NaCl-type of structure), valence υ =2.58 , T-independent (XANES, L₃-edge) **T_N=3.5K, AFM I-type, O.M.=1.7** μ_B (*Tm*²⁺: *J*=7/2 (4.5 μ_B), *Tm*³⁺: *J*=6 (7.5 μ_B)



L3-edge characterization: TmS (3+); TmSe (IV); TmTe (2+).





E. Bucher, e.a. PRB 11 (1) 500 (1975) – magnet susceptibility H. Bjerrum-Moller, S.M. Shapiro, R.J. Birgeneau, PRL 39 (16) 1021 (1977) magnetic structure

H. Launois, M. Rawiso, E.Holland-Moritz, R.Pott, D. Wolleben PRL 44 (19) 1271 (1980) L3-edge

3.2 Intermediate valence and magnetism: TmSe

Neutron spectroscopy (IMNS) for TmSe



M. Loewenhaupt, E. Holland-Moritz, J. Appl. Phys.50 (11) 7456 (1979)



J-M. Mignot, P.A. Alekseev, Physica B 215 (1995) 99-109 "resonance mode" for TmSe: general and specific features



Fig. 7. Neutron scattering spectra of single-crystal TmSe measured in the constant- k_f mode ($E_f = 30.5$ meV) at fixed scattering vectors $\mathbf{Q} = (q, 0, 0)$; (a) q = 1, (b) q = 2, (c) q = 3.

Point of view / Summary 2 / Outlook

CeFe₂Al₁₀

- Conventional Kondo insulator.
- Resonance-like magnetic exciton mode (SmB₆, YbB₁₂)

CeRu₂Al₁₀

- Kondo "insulator" (semimetal) + unconventional magnetic order.
- Existence of clear dispersive magnon-like modes (consistent with RPA calculations).
- Pronounced anisotropy of spin correlations, observed by polarization analysis.
- Ordered phase cannot be reduced to the usual competition CEF + RKKY.
- ➡ Direction dependent hybridization?
- ➡ Localized vs. itinerant approach?

Высокие давления и СКЭС



Некторые проблемы физики конденсированных сред, связанные сильными корреляциями электронов:

- описание электронов, балансирующих между делокализацией и локализацией
- учет сильных корреляций, тяжелые квазичастицы
- квантовые критические точки
- необычная (нефононная) сверхпроводимость (текущий рекорд T_c~20К в PuCoGa₅)

*)P.W. Bridgman, The Physics of High Pressures, G. Bell and Sons, Ltd., London, 1931, p. 267. **)"Challenges in Plutonium Science", ed. N.G. Cooper, Los Alamos Science, Number 26, 2000 Spin fluctuations and magnetism in rare-earth based compounds with *f*-electron instability

Contents

1. Magnetic form factor in intermediate valence state of Sm and Eu

2. Resonance mode in intermediate valence systems: single-site and cooperative behaviour

3. Spin fluctuations and long range magnetic order:

- a case of "strong" intermediate valence
- heavy fermion and Kondo-insulating states